

#### **ABSOLUTE MAXIMUM RATINGS**

at  $T_A = 25^{\circ}C$ 

Logic Supply Voltage, V <sub>DD</sub>	15 V	
Driver Supply Voltage, V <sub>BB</sub>	60 V	)
Continuous Output Current,		

I<sub>OUT</sub>..... -40 mA to +15 mA Input Voltage Range,

V<sub>IN</sub> ..... -0.3 V to V<sub>DD</sub> + 0.3 V Package Power Dissipation, Pp.

(UCQ5818AF)..... 3.5 W\*

(UCQ5818EPF) ...... 2.3 W†

Operating Temperature Range,

T<sub>A</sub> ......-40°C to +85°C Storage Temperature Range,

T<sub>S</sub> ...... -55°C to +150°C

\* Derate at rate of 28 mW/°C above T<sub>A</sub> = +25°C † Derate at rate of 18 mW/°C above T<sub>A</sub> = +25°C

Caution: CMOS devices have input static protection but are susceptible to damage when exposed to extremely high static electrical charges.

Designed primarily for use with vacuum-fluorescent displays, the UCQ5818AF and UCQ5818EPF smart power BiMOS II drivers combine CMOS shift registers, data latches, and control circuitry, with bipolar highspeed sourcing outputs and DMOS active pull-down circuitry. The highspeed shift register and data latches allow direct interfacing with microprocessor LSI-based systems. A CMOS serial data output enables cascade connections in applications requiring additional drive lines. Both devices feature 60 V and -40 mA output ratings, allowing them to be used in many other peripheral power driver applications.

These smart power drivers have been designed with BiMOS II logic for improved data entry rates. With a 5 V supply, they will operate to at least 3.3 MHz. At 12 V, higher speeds are possible. Use of these devices with TTL may require the use of appropriate pull-up resistors to ensure an input logic high. All devices can be operated over the ambient temperature range of -40°C to +85°C. The UCQ5818AF is supplied in a 40-pin plastic dual in-line package with 0.600" (15.24 mm) row spacing. A copper lead frame, reduced supply current requirement, and low output saturation voltage permits operation with minimum junction temperature rise. The 'A' package allows all 32 outputs to be operated at -25 mA continuously over the operating temperature range.

For high-density packaging applications, the UCQ5818EPF is furnished in a 44-lead plastic chip carrier (quad pack) for surface mounting on solder lands with 0.050" (1.27 mm) centers. The PLCC allows -25 mA continuous operation of all outputs simultaneously at ambient temperatures to 60°C. Similar devices are available as the UCQ5810AF/LWF (10 bits), UCQ5811A (12 bits), and UCQ5812AF/EPF (20 bits).

#### **FEATURES**

- 60 V Source Outputs
- **High-Speed Source Drivers**
- To 3.3 MHz Data Input Rate
- Low-Output Saturation Voltages
- Active DMOS Pull-Downs
- Low-Power CMOS Logic and Latches
- Reduced Supply Current Requirements
- Improved Replacements for SN75518N/FN

Always order by complete part number, e.g., | UCQ5818EPF|.

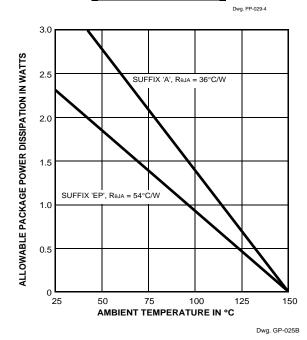


#### LOAD SUPPLY 40 LOGIC SUPPLY 39 SERIAL DATA IN SERIAL DATA OUT 38 OUT 1 OUT<sub>2</sub> 36 OUT 3 34 OUT<sub>5</sub> OUT<sub>27</sub> REGISTER REGISTER LATCHES 29 OUT 10 OUT 23 12 OUT<sub>22</sub> 13 27 OUT 12 OUT 20 15 OUT<sub>19</sub> 16

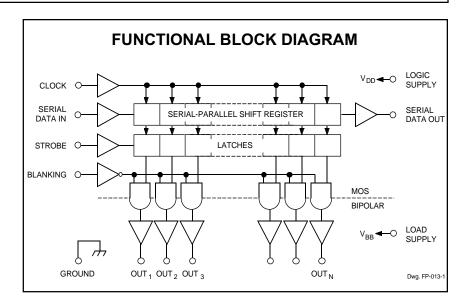
24 OUT <sub>15</sub>

ST 22 STROBE

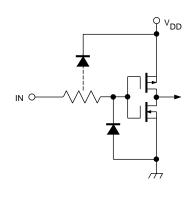
**UCQ5818AF** 



OUT<sub>17</sub> 18
BLANKING 19

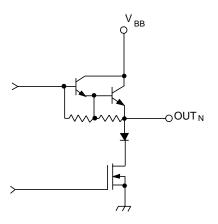


#### TYPICAL INPUT CIRCUIT



Dwg. EP-010-5

#### TYPICAL OUTPUT DRIVER



Dwg. No. A-14,219

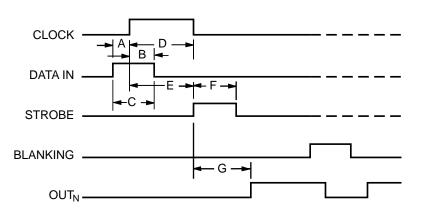


# ELECTRICAL CHARACTERISTICS over operating temperature range, $V_{BB}$ = 60 V unless otherwise noted.

			Limits @ V <sub>DD</sub> = 5 V			Limits			
Characteristic	Symbol	Test Conditions	MIn.	Тур.	Max.	Min.	Тур.	Max.	Units
Output Leakage Current	I <sub>CEX</sub>	V <sub>OUT</sub> = 0 V, T <sub>A</sub> = +70°C	_	-5.0	-15	_	-5.0	-15	μΑ
Output Voltage	V <sub>OUT(1)</sub>	I <sub>OUT</sub> = -25 mA	58	58.5	_	58	58.5	_	V
	V <sub>OUT(0)</sub>	I <sub>OUT</sub> = 1 mA	_	2.0	3.0	_	_	_	V
		I <sub>OUT</sub> = 2 mA	_	_	_	_	2.0	3.5	V
Output Pull-Down Current	I <sub>OUT(0)</sub>	V <sub>OUT</sub> = 5 V to V <sub>BB</sub>	2.0	3.5	_	_	_	_	mA
		V <sub>OUT</sub> = 20 V to V <sub>BB</sub>	_	_	_	8.0	13	_	mA
Input Voltage	V <sub>IN(1)</sub>		3.5	_	5.3	10.5	_	12.3	V
	V <sub>IN(0)</sub>		-0.3	_	+0.8	-0.3	_	+0.8	V
Input Current	I <sub>IN(1)</sub>	$V_{IN} = V_{DD}$	_	0.05	0.5	_	0.1	1.0	μΑ
	I <sub>IN(0)</sub>	V <sub>IN</sub> = 0.8 V	_	-0.05	-0.5	_	-0.1	-1.0	μΑ
Serial Data Output Voltage	V <sub>OUT(1)</sub>	I <sub>OUT</sub> = -200 μA	4.5	4.7	_	11.7	11.8	_	V
	V <sub>OUT(0)</sub>	I <sub>OUT</sub> = 200 μA	_	200	250	_	100	200	mV
Maximum Clock Frequency	f <sub>clk</sub>		3.3*	_	_	_	_	_	MHz
Supply Current	I <sub>DD(1)</sub>	All Outputs High	_	100	300	_	200	500	μΑ
	I <sub>DD(0)</sub>	All Outputs Low	_	100	300	_	200	500	μΑ
	I <sub>BB(1)</sub>	Outputs High, No Load	_	3.0	6.0	_	3.0	6.0	mA
	I <sub>BB(0)</sub>	Outputs Low	_	10	100	_	10	100	μΑ
Blanking to Output Delay	t <sub>PHL</sub>	C <sub>L</sub> = 30 pF, 50% to 50%	_	2000	_	_	1000	_	ns
	t <sub>PLH</sub>	C <sub>L</sub> = 30 pF, 50% to 50%	_	1000	_	_	850	_	ns
Output Fall Time	t <sub>f</sub>	C <sub>L</sub> = 30 pF, 90% to 10%	_	1450	_	_	650	_	ns
Output Rise Time	t <sub>r</sub>	C <sub>L</sub> = 30 pF, 10% to 90%	_	650	_	_	700	_	ns

Negative current is defined as coming out of (sourcing) the specified device pin.

<sup>\*</sup> Operation at a clock frequency greater than the specified minimum value is possible but not warranteed.



Dwg. No. A-12,649A

#### TIMING REQUIREMENTS

 $(T_A = +25^{\circ}C, V_{DD} = 5 \text{ V}, \text{Logic Levels are } V_{DD} \text{ and Ground})$ 

A.	Minimum Data Active Time Before Clock Pulse (Data Set-Up Time)	. 75 ns
В.	Minimum Data Active Time After Clock Pulse (Data Hold Time)	. 75 ns
C.	Minimum Data Pulse Width	150 ns
D.	Minimum Clock Pulse Width	150 ns
E.	Minimum Time Between Clock Activation and Strobe	300 ns
F.	Minimum Strobe Pulse Width	100 ns
G.	Typical Time Between Strobe Activation and Output Transistion	500 ns

Timing is representative of a 3.3 MHz clock. Higher speeds may be attainable with increased supply voltage; operation at high temperatures will reduce the specified maximum clock frequency.

Serial Data present at the input is transferred to the shift register on the logic "0" to logic "1" transition of the CLOCK input pulse. On succeeding CLOCK pulses, the registers shift data information towards the SERIAL DATA OUT-PUT. The SERIAL DATA must appear at the input prior to the rising edge of the CLOCK input waveform.

Information present at any register is transferred to the respective latch when the STROBE is high (serial-to-parallel conversion). The latches will continue to accept new data as long as the STROBE is held high. Applications where the latches are bypassed (STROBE tied high) will require that the BLANKING input be high during serial data entry.

When the BLANKING input is high, the output source drivers are disabled (OFF); the DMOS sink drivers are ON, the information stored in the latches is not affected by the BLANKING input. With the BLANKING input low, the outputs are controlled by the state of their respective latches.

#### **TRUTH TABLE**

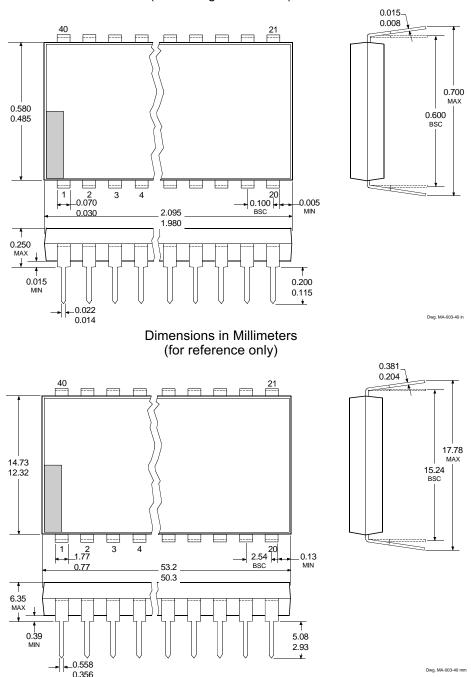
Serial			hift	Regi	ister	Conte	ents	Serial			Lat	ch (	Conte	ents			Output Contents						
Data Input	Clock		l <sub>2</sub>	I <sub>3</sub>		I <sub>N-1</sub>	I <sub>N</sub>	Data Output	Strobe Input	l <sub>1</sub>	I <sub>2</sub>	l <sub>3</sub>		I <sub>N-1</sub>	I <sub>N</sub>	Blanking	I <sub>1</sub>	I <sub>2</sub>	I <sub>3</sub>	I <sub>l</sub>	N-1	I <sub>N</sub>	
Н		Н	R <sub>1</sub>	R <sub>2</sub>		R <sub>N-2</sub>	R <sub>N-1</sub>	R <sub>N-1</sub>															
L	丁	L	R <sub>1</sub>	$R_2$		R <sub>N-2</sub>	R <sub>N-1</sub>	R <sub>N-1</sub>															
Х		$R_1$	$R_2$	$R_3$		R <sub>N-1</sub>	$R_{N}$	R <sub>N</sub>															
		Χ	Χ	Х		Χ	Χ	Х	L	R <sub>1</sub>	$R_2$	$R_3$		R <sub>N-1</sub>	$R_{N}$								
		P <sub>1</sub>	P <sub>2</sub>	P <sub>3</sub>		P <sub>N-1</sub>	P <sub>N</sub>	P <sub>N</sub>	Н	P <sub>1</sub>	P <sub>2</sub>	P <sub>3</sub>		P <sub>N-1</sub>	$P_{N}$	L	P <sub>1</sub>	P <sub>2</sub>	P <sub>3</sub>	F	N-1	P <sub>N</sub>	
						•				Х	Х	Х		X	Х	Н	L	L	L	L	-	L	

L = Low Logic Level H = High Logic Level X = Irrelevant P = Present State R = Previous State



#### **UCQ5818AF**

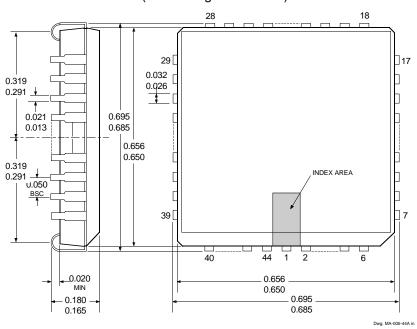
Dimensions in Inches (controlling dimensions)



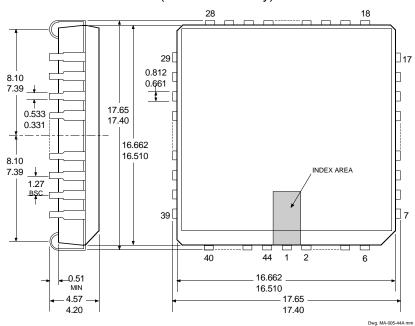
- NOTES: 1. Exact body and lead configuration at vendor's option within limits shown.
  - 2. Lead spacing tolerance is non-cumulative.
  - 3. Lead thickness is measured at seating plane or below.
  - 4. Supplied in standard sticks/tubes of 9 devices.

#### UCQ5818EPF

Dimensions in Inches (contrrolling dimensions)



# Dimensions in Millimeters (for reference only)



- NOTES: 1. Exact body and lead configuration at vendor's option within limits shown.
  - 2. Lead spacing tolerance is non-cumulative.
  - 3. Supplied in standard sticks/tubes of 27 devices or add "TR" to part number for tape and reel.



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# POWER INTERFACE DRIVERS

Function	Output l	Ratings*	Part Number <sup>†</sup>							
SERIAL-INPUT LATCHED DRIVERS										
8-Bit (saturated drivers)	-120 mA	50 V‡	5895							
8-Bit	350 mA	50 V	5821							
8-Bit	350 mA	80 V	5822							
8-Bit	350 mA	50 V‡	5841							
8-Bit	350 mA	80 V‡	5842							
8-Bit (constant-current LED driver)	75 mA	17 V	6275							
8-Bit (constant-current LED driver)	120 mA	24 V	6277							
8-Bit (DMOS drivers)	250 mA	50 V	6595							
8-Bit (DMOS drivers)	350 mA	50 V‡	6A595							
8-Bit (DMOS drivers)	100 mA	50 V	6B595							
10-Bit (active pull-downs)	-25 mA	60 V	5810-F and 6810							
12-Bit (active pull-downs)	-25 mA	60 V	5811							
16-Bit (constant-current LED driver)	75 mA	17 V	6276							
20-Bit (active pull-downs)	-25 mA	60 V	5812-F and 6812							
32-Bit (active pull-downs)	-25 mA	60 V	5818-F and 6818							
32-Bit	100 mA	30 V	5833							
32-Bit (saturated drivers)	100 mA	40 V	5832							
PARALLEI	-INPUT LATCHED	DRIVERS								
4-Bit	350 mA	50 V‡	5800							
8-Bit	-25 mA	60 V	5815							
8-Bit	350 mA	50 V‡	5801							
8-Bit (DMOS drivers)	100 mA	50 V	6B273							
8-Bit (DMOS drivers)	250 mA	50 V	6273							
SPECI	AL-PURPOSE DEV	ICES								
Unipolar Stepper Motor Translator/Driver	1.25 A	50 V‡	5804							
Addressable 8-Bit Decoder/DMOS Driver	250 mA	50 V	6259							
Addressable 8-Bit Decoder/DMOS Driver	350 mA	50 V‡	6A259							
Addressable 8-Bit Decoder/DMOS Driver	100 mA	50 V	6B259							
Addressable 28-Line Decoder/Driver	450 mA	30 V	6817							

<sup>\*</sup> Current is maximum specified test condition, voltage is maximum rating. See specification for sustaining voltage limits. Negative current is defined as coming out of (sourcing) the output.

<sup>‡</sup> Internal transient-suppression diodes included for inductive-load protection.



<sup>†</sup> Complete part number includes additional characters to indicate operating temperature range and package style.